

MC33201, MC33202, MC33204

Rail-to-Rail Operational Amplifiers

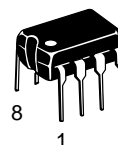
The MC33201/2/4 family of operational amplifiers provide rail-to-rail operation on both the input and output. The inputs can be driven as high as 200 mV beyond the supply rails without phase reversal on the outputs, and the output can swing within 50 mV of each rail. This rail-to-rail operation enables the user to make full use of the supply voltage range available. It is designed to work at very low supply voltages (± 0.9 V) yet can operate with a supply of up to +12 V and ground. Output current boosting techniques provide a high output current capability while keeping the drain current of the amplifier to a minimum. Also, the combination of low noise and distortion with a high slew rate and drive capability make this an ideal amplifier for audio applications.

- Low Voltage, Single Supply Operation
(+1.8 V and Ground to +12 V and Ground)
- Input Voltage Range Includes both Supply Rails
- Output Voltage Swings within 50 mV of both Rails
- No Phase Reversal on the Output for Over-driven Input Signals
- High Output Current ($I_{SC} = 80$ mA, Typ)
- Low Supply Current ($I_D = 0.9$ mA, Typ)
- 600 Ω Output Drive Capability
- Extended Operating Temperature Ranges
(-40° to $+105^\circ\text{C}$ and -55° to $+125^\circ\text{C}$)
- Typical Gain Bandwidth Product = 2.2 MHz



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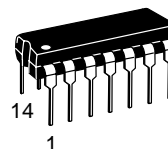
PDIP-8
P, VP SUFFIX
CASE 626



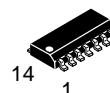
SO-8
D, VD SUFFIX
CASE 751



Micro-8
DM SUFFIX
CASE 846A



PDIP-14
P, VP SUFFIX
CASE 646



SO-14
D, VD SUFFIX
CASE 751A



TSSOP-14
DTB SUFFIX
CASE 948G

ORDERING INFORMATION

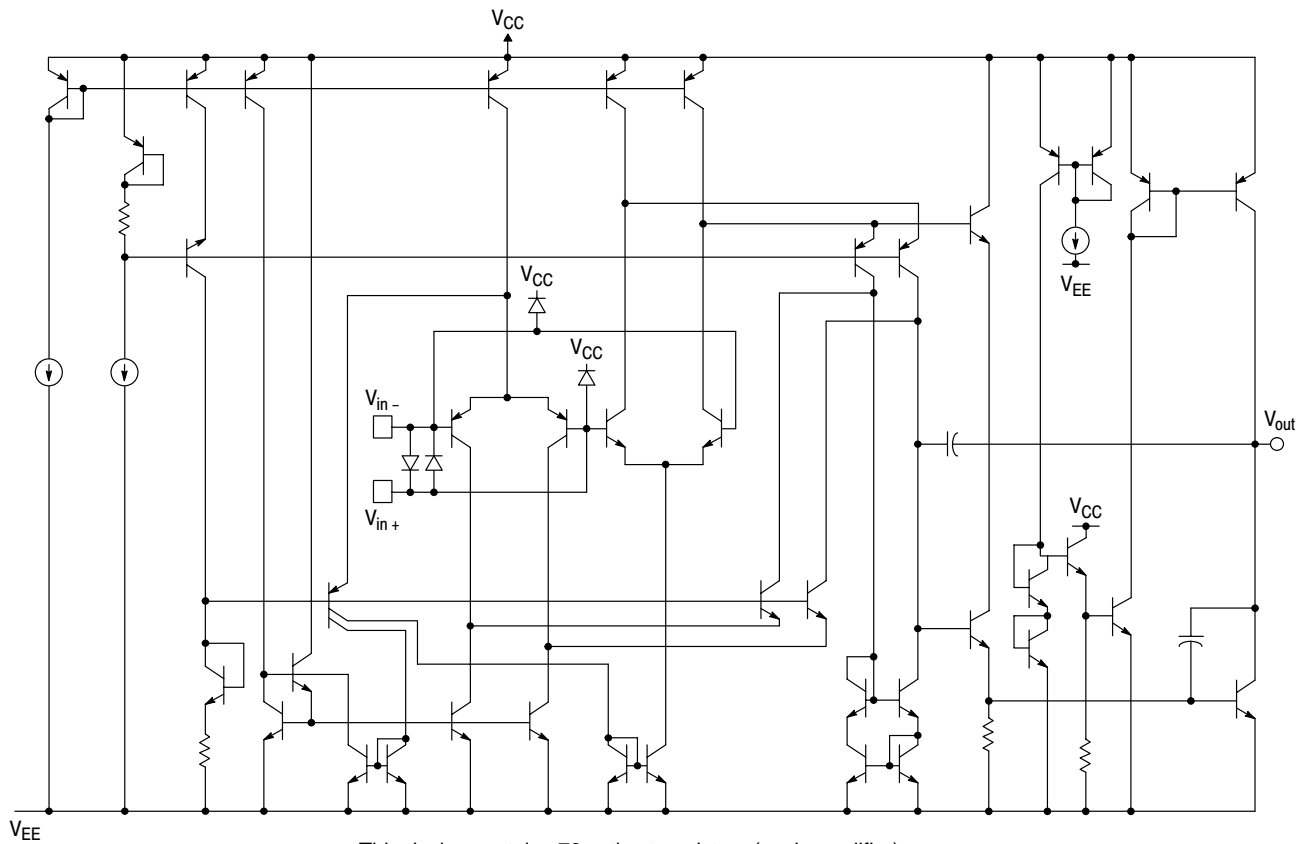
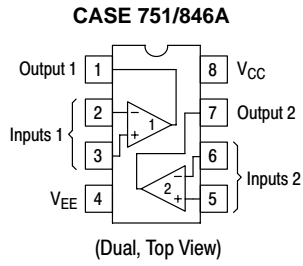
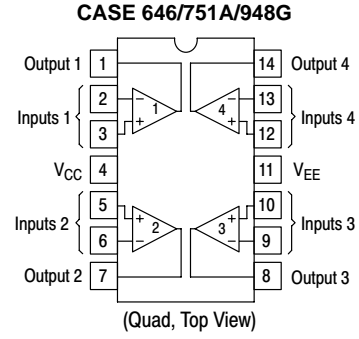
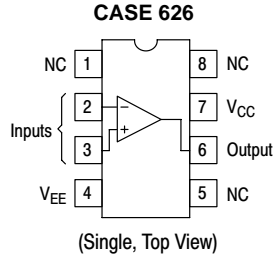
See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 11 of this data sheet.

MC33201, MC33202, MC33204

PIN CONNECTIONS



This device contains 70 active transistors (each amplifier).

Figure 1. Circuit Schematic
(Each Amplifier)

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage (V_{CC} to V_{EE})	V_S	+13	V
Input Differential Voltage Range	V_{IDR}	Note 1.	V
Common Mode Input Voltage Range (Note 2.)	V_{CM}	$V_{CC} + 0.5$ V to $V_{EE} - 0.5$ V	V
Output Short Circuit Duration	t_s	Note 3.	sec
Maximum Junction Temperature	T_J	+150	°C
Storage Temperature	T_{stg}	- 65 to +150	°C
Maximum Power Dissipation	P_D	Note 3.	mW

DC ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

Characteristic	$V_{CC} = 2.0$ V	$V_{CC} = 3.3$ V	$V_{CC} = 5.0$ V	Unit
Input Offset Voltage $V_{IO}(\text{max})$ MC33201 MC33202 MC33204	± 8.0 ± 10 ± 12	± 8.0 ± 10 ± 12	± 6.0 ± 8.0 ± 10	mV
Output Voltage Swing V_{OH} ($R_L = 10$ k Ω) V_{OL} ($R_L = 10$ k Ω)	1.9 0.10	3.15 0.15	4.85 0.15	V_{\min} V_{\max}
Power Supply Current per Amplifier (I_D)	1.125	1.125	1.125	mA

Specifications at $V_{CC} = 3.3$ V are guaranteed by the 2.0 V and 5.0 V tests. $V_{EE} = \text{Gnd}$.

DC ELECTRICAL CHARACTERISTICS ($V_{CC} = +5.0$ V, $V_{EE} = \text{Ground}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

Characteristic	Figure	Symbol	Min	Typ	Max	Unit
Input Offset Voltage ($V_{CM} = 0$ V to 0.5 V, $V_{CM} = 1.0$ V to 5.0 V) MC33201: $T_A = +25^\circ\text{C}$ MC33201: $T_A = -40^\circ$ to $+105^\circ\text{C}$ MC33201V: $T_A = -55^\circ$ to $+125^\circ\text{C}$ MC33202: $T_A = +25^\circ\text{C}$ MC33202: $T_A = -40^\circ$ to $+105^\circ\text{C}$ MC33202V: $T_A = -55^\circ$ to $+125^\circ\text{C}$ MC33204: $T_A = +25^\circ\text{C}$ MC33204: $T_A = -40^\circ$ to $+105^\circ\text{C}$ MC33204V: $T_A = -55^\circ$ to $+125^\circ\text{C}$	3	$ V_{IO} $	- - - - - - - - -	- - - - - - - - -	6.0 9.0 13 8.0 11 14 10 13 17	mV
Input Offset Voltage Temperature Coefficient ($R_S = 50$ Ω) $T_A = -40^\circ$ to $+105^\circ\text{C}$ $T_A = -55^\circ$ to $+125^\circ\text{C}$	4	$\Delta V_{IO}/\Delta T$	- -	2.0 2.0	- -	$\mu\text{V}/^\circ\text{C}$
Input Bias Current ($V_{CM} = 0$ V to 0.5 V, $V_{CM} = 1.0$ V to 5.0 V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+105^\circ\text{C}$ $T_A = -55^\circ$ to $+125^\circ\text{C}$	5, 6	$ I_{IB} $	- - -	80 100 -	200 250 500	nA
Input Offset Current ($V_{CM} = 0$ V to 0.5 V, $V_{CM} = 1.0$ V to 5.0 V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+105^\circ\text{C}$ $T_A = -55^\circ$ to $+125^\circ\text{C}$	-	$ I_{IO} $	- - -	5.0 10 -	50 100 200	nA
Common Mode Input Voltage Range	-	V_{ICR}	V_{EE}	-	V_{CC}	V

- The differential input voltage of each amplifier is limited by two internal parallel back-to-back diodes. For additional differential input voltage range, use current limiting resistors in series with the input pins.
- The input common mode voltage range is limited by internal diodes connected from the inputs to both supply rails. Therefore, the voltage on either input must not exceed either supply rail by more than 500 mV.
- Power dissipation must be considered to ensure maximum junction temperature (T_J) is not exceeded. (See Figure 2)

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DC ELECTRICAL CHARACTERISTICS (cont.) ($V_{CC} = +5.0\text{ V}$, $V_{EE} = \text{Ground}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

Characteristic	Figure	Symbol	Min	Typ	Max	Unit
Large Signal Voltage Gain ($V_{CC} = +5.0\text{ V}$, $V_{EE} = -5.0\text{ V}$) $R_L = 10\text{ k}\Omega$ $R_L = 600\ \Omega$	7	A_{VOL}	50 25	300 250	– –	kV/V
Output Voltage Swing ($V_{ID} = \pm 0.2\text{ V}$) $R_L = 10\text{ k}\Omega$ $R_L = 10\text{ k}\Omega$ $R_L = 600\ \Omega$ $R_L = 600\ \Omega$	8, 9, 10	V_{OH} V_{OL} V_{OH} V_{OL}	4.85 – 4.75 –	4.95 0.05 4.85 0.15	– 0.15 – 0.25	V
Common Mode Rejection ($V_{in} = 0\text{ V}$ to 5.0 V)	11	CMR	60	90	–	dB
Power Supply Rejection Ratio $V_{CC}/V_{EE} = 5.0\text{ V/Gnd}$ to 3.0 V/Gnd	12	PSRR	500	25	–	$\mu\text{V/V}$
Output Short Circuit Current (Source and Sink)	13, 14	I_{SC}	50	80	–	mA
Power Supply Current per Amplifier ($V_O = 0\text{ V}$) $T_A = -40^\circ$ to $+105^\circ\text{C}$ $T_A = -55^\circ$ to $+125^\circ\text{C}$	15	I_D	– –	0.9 0.9	1.125 1.125	mA

AC ELECTRICAL CHARACTERISTICS ($V_{CC} = +5.0\text{ V}$, $V_{EE} = \text{Ground}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

Characteristic	Figure	Symbol	Min	Typ	Max	Unit
Slew Rate ($V_S = \pm 2.5\text{ V}$, $V_O = -2.0\text{ V}$ to $+2.0\text{ V}$, $R_L = 2.0\text{ k}\Omega$, $A_V = +1.0$)	16, 26	SR	0.5	1.0	–	V/ μs
Gain Bandwidth Product ($f = 100\text{ kHz}$)	17	GBW	–	2.2	–	MHz
Gain Margin ($R_L = 600\ \Omega$, $C_L = 0\text{ pF}$)	20, 21, 22	A_M	–	12	–	dB
Phase Margin ($R_L = 600\ \Omega$, $C_L = 0\text{ pF}$)	20, 21, 22	θ_M	–	65	–	Deg
Channel Separation ($f = 1.0\text{ Hz}$ to 20 kHz , $A_V = 100$)	23	CS	–	90	–	dB
Power Bandwidth ($V_O = 4.0\text{ V}_{pp}$, $R_L = 600\ \Omega$, $\text{THD} \leq 1\%$)		BW_P	–	28	–	kHz
Total Harmonic Distortion ($R_L = 600\ \Omega$, $V_O = 1.0\text{ V}_{pp}$, $A_V = 1.0$) $f = 1.0\text{ kHz}$ $f = 10\text{ kHz}$	24	THD	– –	0.002 0.008	– –	%
Open Loop Output Impedance ($V_O = 0\text{ V}$, $f = 2.0\text{ MHz}$, $A_V = 10$)		$ Z_O $	–	100	–	Ω
Differential Input Resistance ($V_{CM} = 0\text{ V}$)		R_{in}	–	200	–	k Ω
Differential Input Capacitance ($V_{CM} = 0\text{ V}$)		C_{in}	–	8.0	–	pF
Equivalent Input Noise Voltage ($R_S = 100\ \Omega$) $f = 10\text{ Hz}$ $f = 1.0\text{ kHz}$	25	e_n	– –	25 20	– –	nV/ $\sqrt{\text{Hz}}$
Equivalent Input Noise Current $f = 10\text{ Hz}$ $f = 1.0\text{ kHz}$	25	i_n	– –	0.8 0.2	– –	pA/ $\sqrt{\text{Hz}}$

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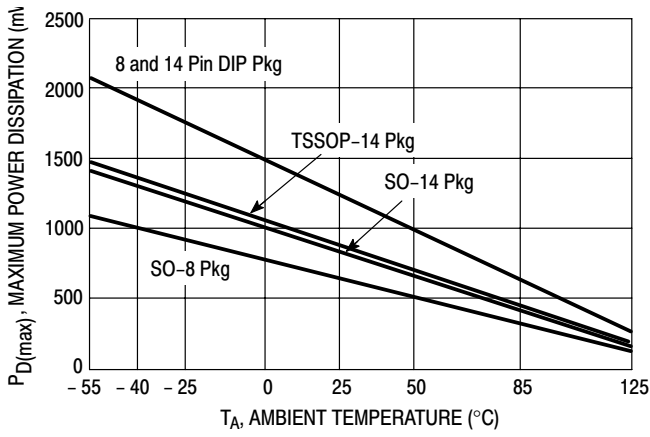


Figure 2. Maximum Power Dissipation versus Temperature

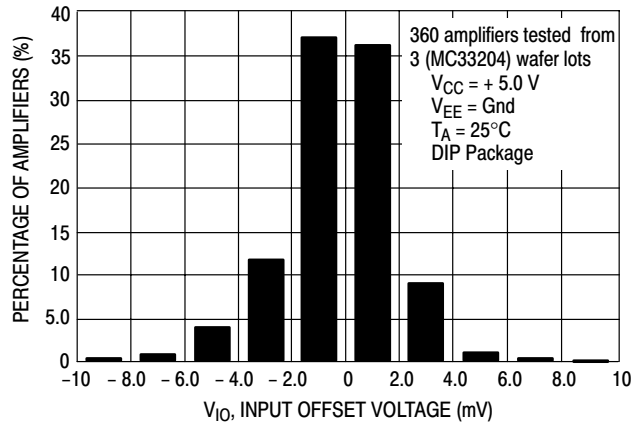


Figure 3. Input Offset Voltage Distribution

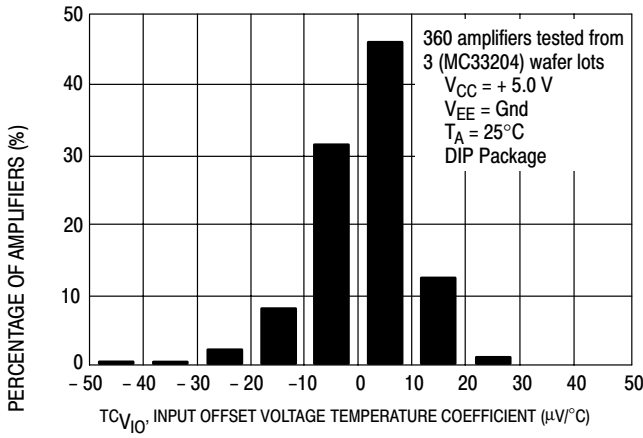


Figure 4. Input Offset Voltage Temperature Coefficient Distribution

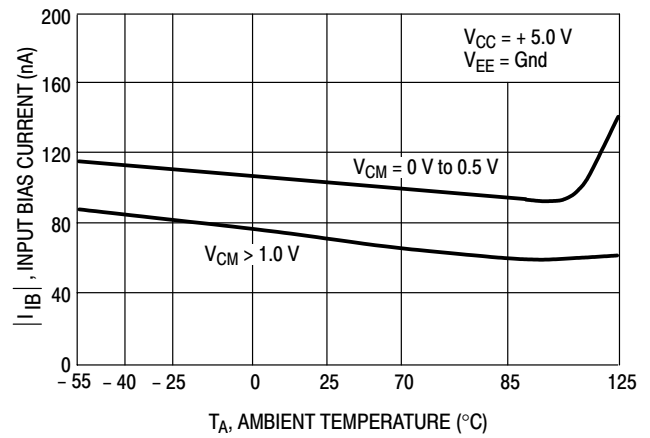


Figure 5. Input Bias Current versus Temperature

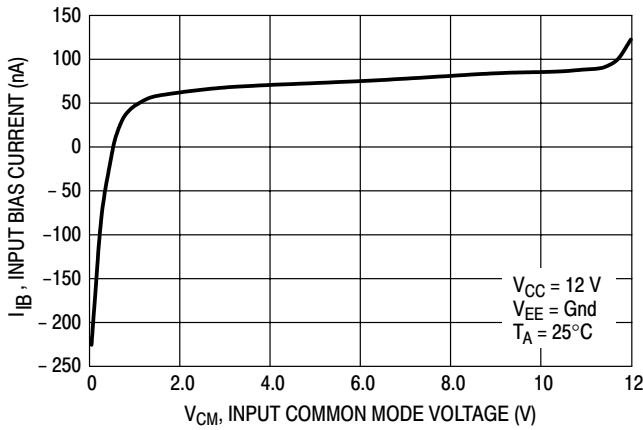


Figure 6. Input Bias Current versus Common Mode Voltage

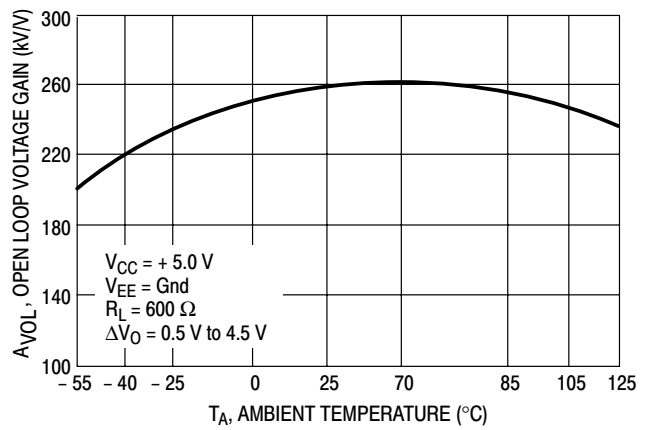


Figure 7. Open Loop Voltage Gain versus Temperature

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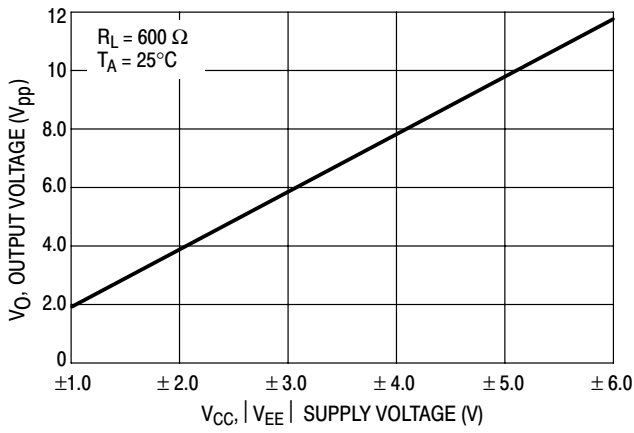


Figure 8. Output Voltage Swing versus Supply Voltage

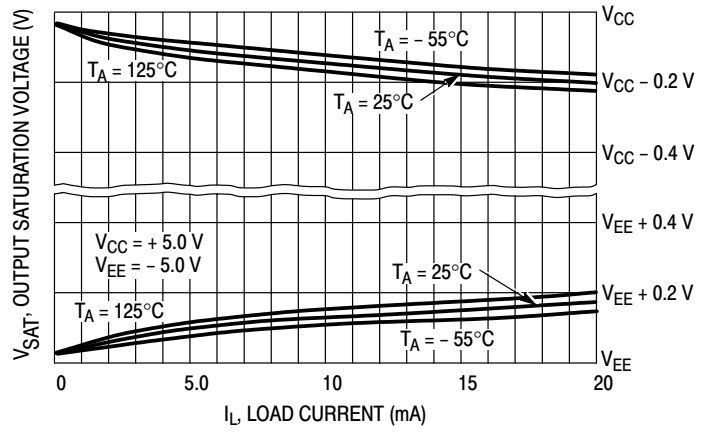


Figure 9. Output Saturation Voltage versus Load Current

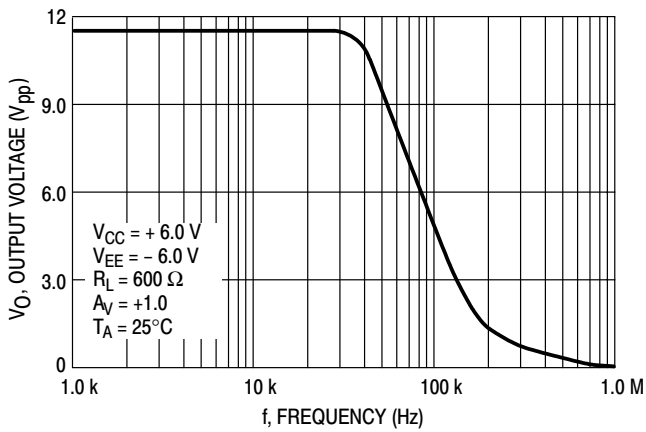


Figure 10. Output Voltage versus Frequency

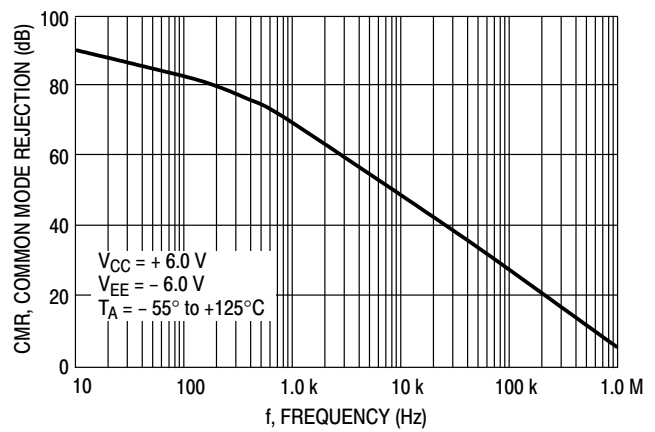


Figure 11. Common Mode Rejection versus Frequency

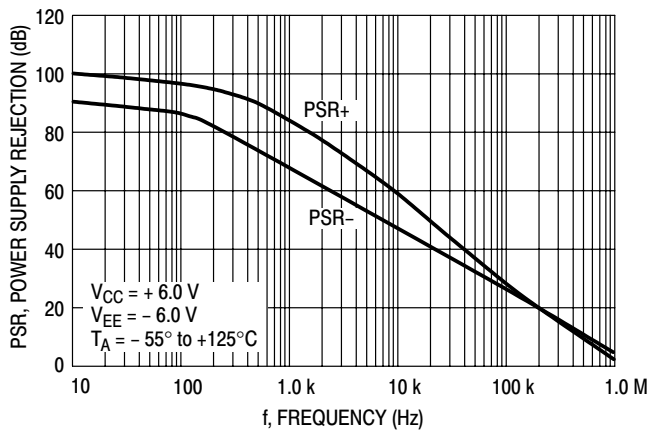


Figure 12. Power Supply Rejection versus Frequency

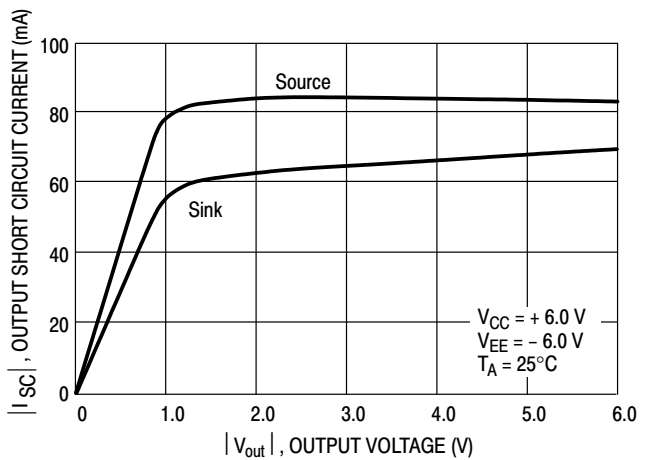


Figure 13. Output Short Circuit Current versus Output Voltage

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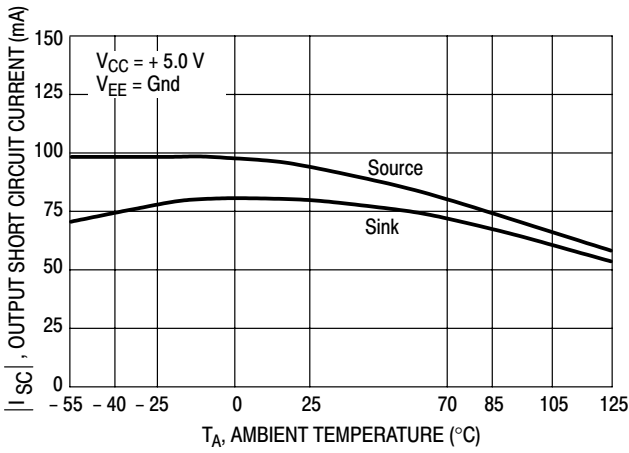


Figure 14. Output Short Circuit Current versus Temperature

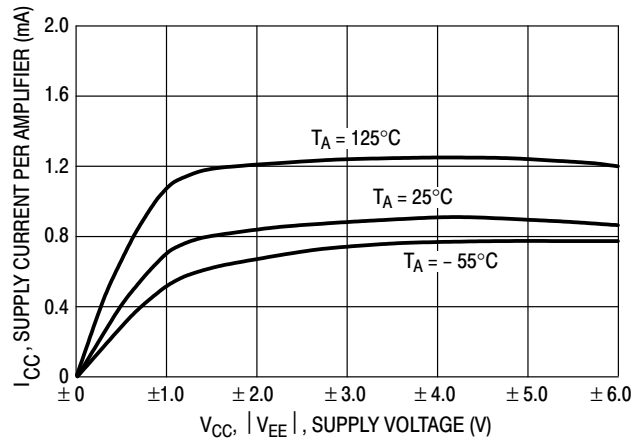


Figure 15. Supply Current per Amplifier versus Supply Voltage with No Load

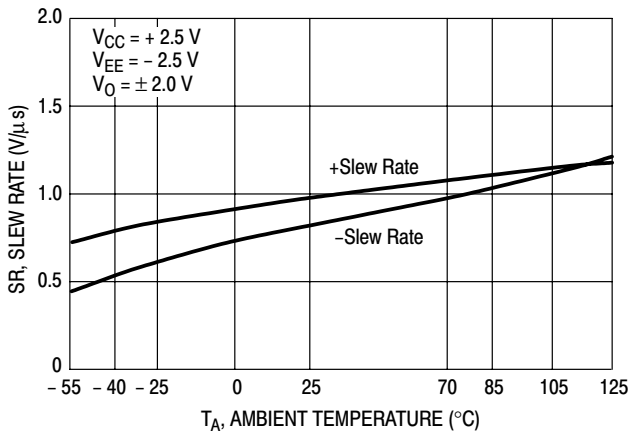


Figure 16. Slew Rate versus Temperature

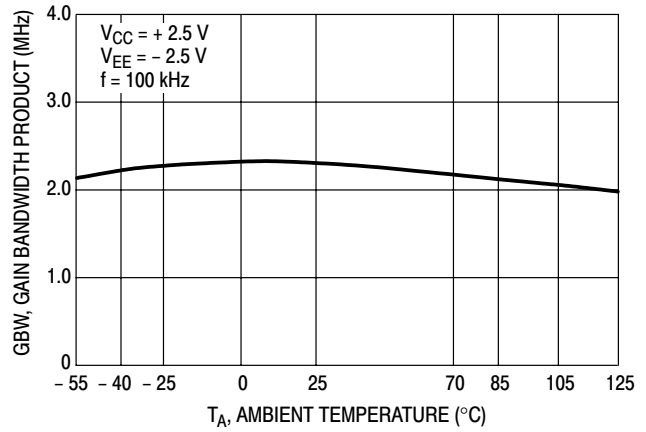


Figure 17. Gain Bandwidth Product versus Temperature

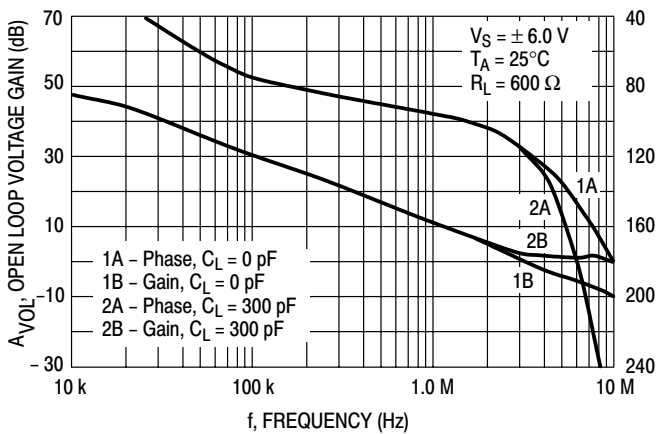


Figure 18. Voltage Gain and Phase versus Frequency

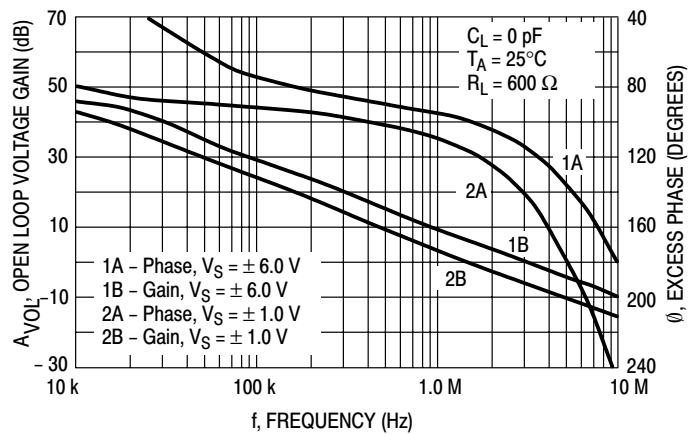


Figure 19. Voltage Gain and Phase versus Frequency

MC33201, MC33202, MC33204

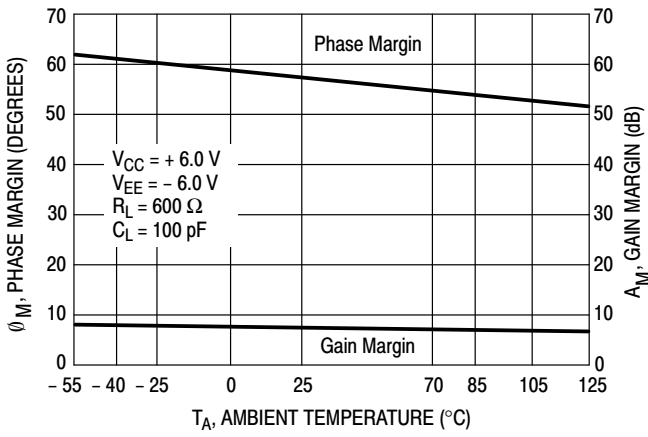


Figure 20. Gain and Phase Margin versus Temperature

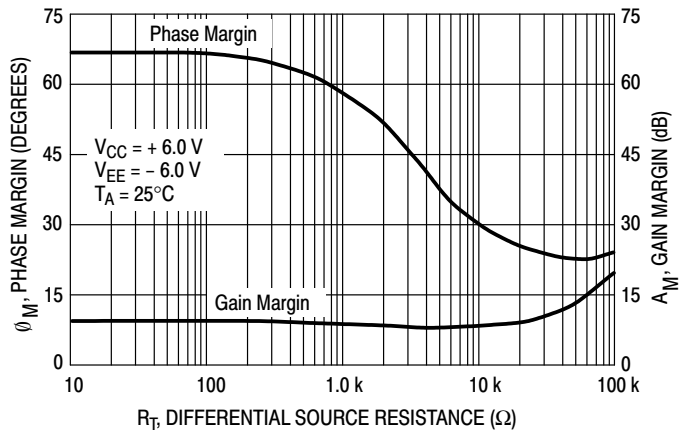


Figure 21. Gain and Phase Margin versus Differential Source Resistance

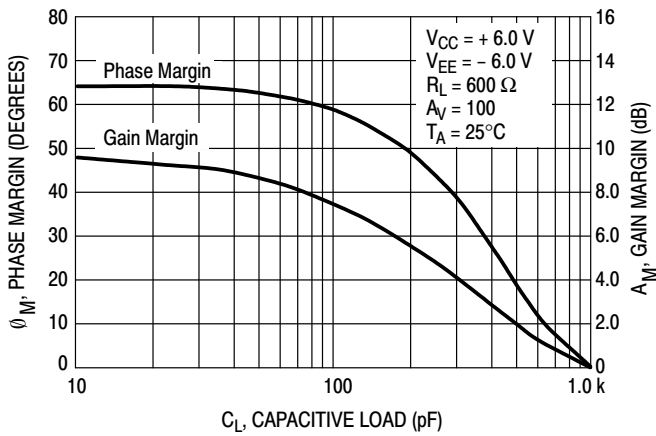


Figure 22. Gain and Phase Margin versus Capacitive Load

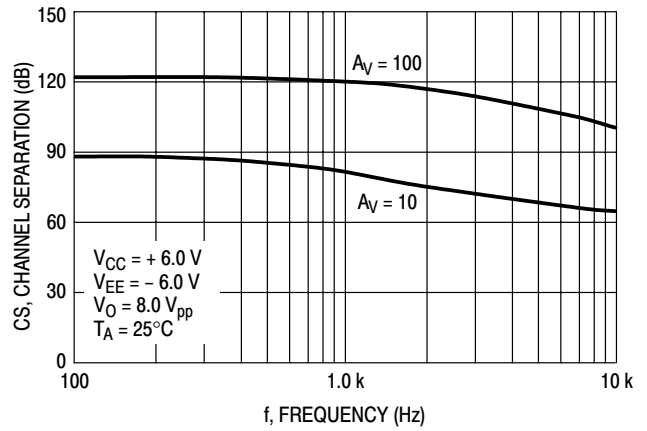


Figure 23. Channel Separation versus Frequency

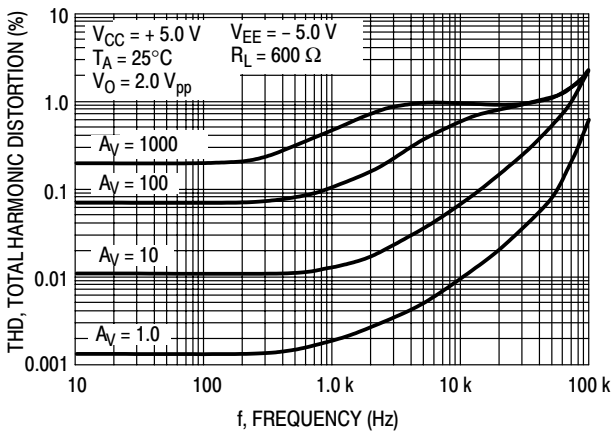


Figure 24. Total Harmonic Distortion versus Frequency

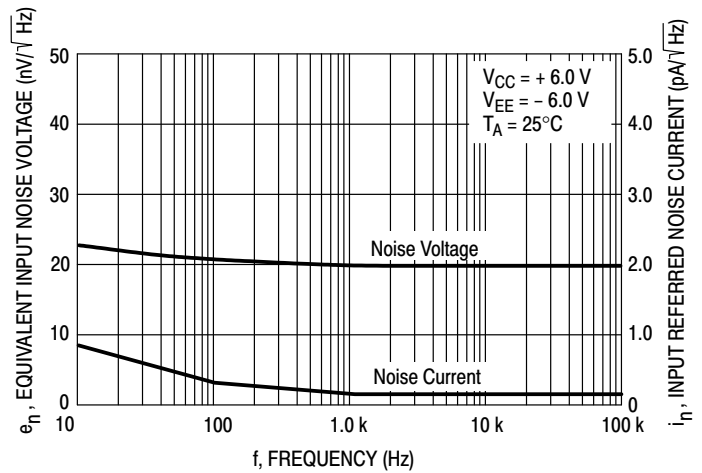


Figure 25. Equivalent Input Noise Voltage and Current versus Frequency

DETAILED OPERATING DESCRIPTION

General Information

The MC33201/2/4 family of operational amplifiers are unique in their ability to swing rail-to-rail on both the input and the output with a completely bipolar design. This offers low noise, high output current capability and a wide common mode input voltage range even with low supply voltages. Operation is guaranteed over an extended temperature range and at supply voltages of 2.0 V, 3.3 V and 5.0 V and ground.

Since the common mode input voltage range extends from V_{CC} to V_{EE} , it can be operated with either single or split voltage supplies. The MC33201/2/4 are guaranteed not to latch or phase reverse over the entire common mode range, however, the inputs should not be allowed to exceed maximum ratings.

Circuit Information

Rail-to-rail performance is achieved at the input of the amplifiers by using parallel NPN-PNP differential input stages. When the inputs are within 800 mV of the negative rail, the PNP stage is on. When the inputs are more than 800 mV greater than V_{EE} , the NPN stage is on. This switching of input pairs will cause a reversal of input bias currents (see Figure 6). Also, slight differences in offset voltage may be noted between the NPN and PNP pairs. Cross-coupling techniques have been used to keep this change to a minimum.

In addition to its rail-to-rail performance, the output stage is current boosted to provide 80 mA of output current, enabling the op amp to drive 600 Ω loads. Because of this high output current capability, care should be taken not to exceed the 150°C maximum junction temperature.

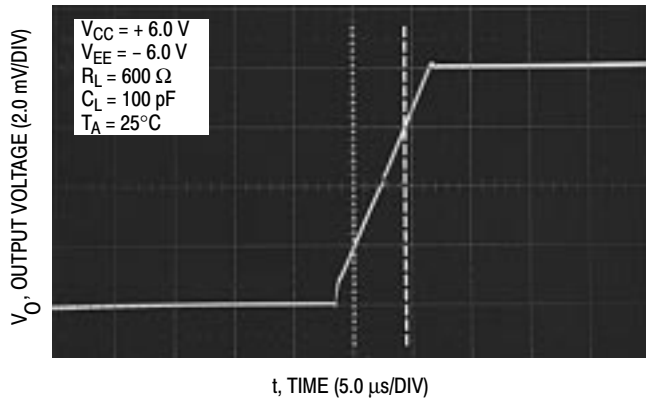


Figure 26. Noninverting Amplifier Slew Rate

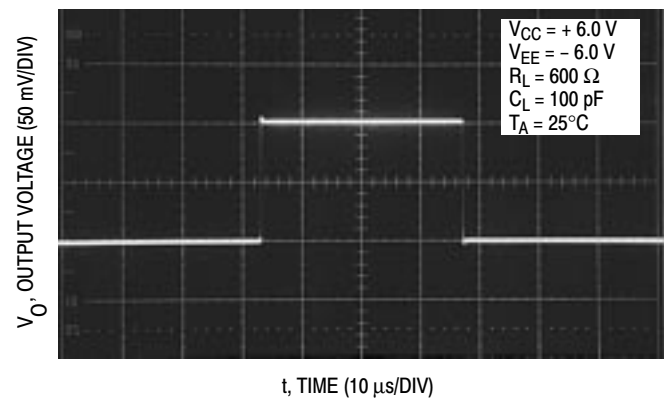


Figure 27. Small Signal Transient Response

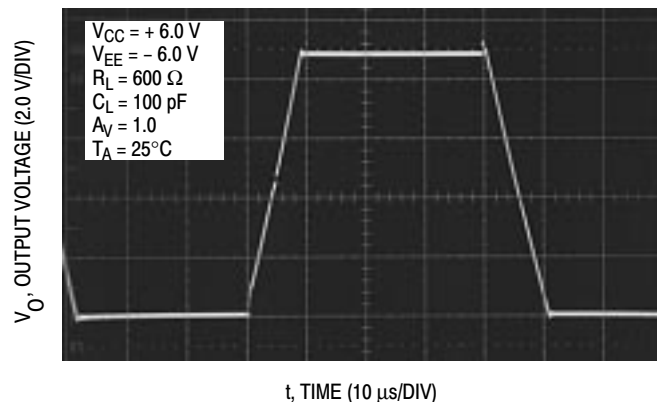


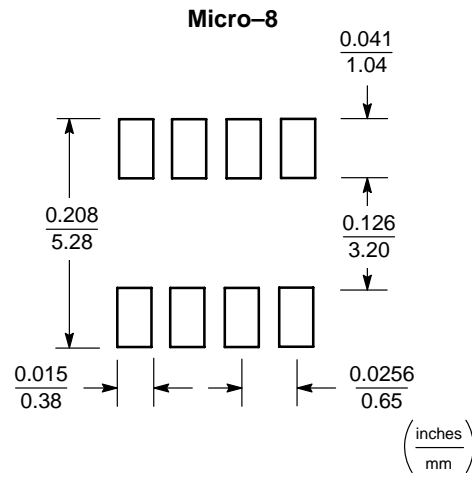
Figure 28. Large Signal Transient Response

MC33201, MC33202, MC33204

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to ensure proper solder connection interface

between the board and the package. With the correct pad geometry, the packages will self-align when subjected to a solder reflow process.

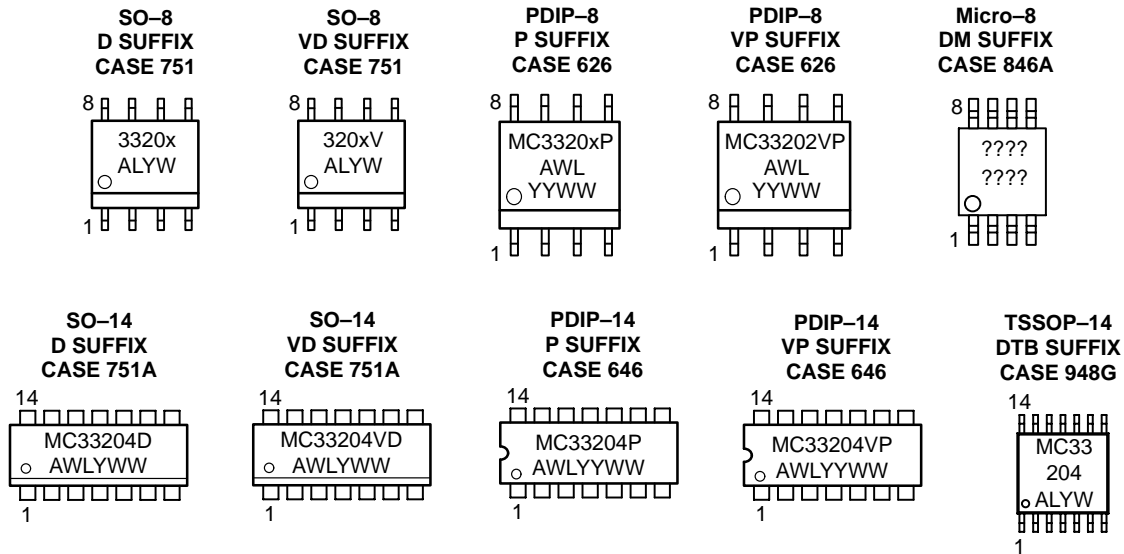


MC33201, MC33202, MC33204

ORDERING INFORMATION

Operational Amplifier Function	Device	Operating Temperature Range	Package	Shipping
Single	MC33201D	$T_A = -40^\circ \text{ to } +105^\circ \text{C}$	SO-8	98 Units / Rail
	MC33201DR2		SO-8	2500 Units / Tape & Reel
	MC33201P		Plastic DIP	50 Units / Rail
	MC33201VD	$T_A = -55^\circ \text{ to } 125^\circ \text{C}$	SO-8	98 Units / Rail
Dual	MC33202D	$T_A = -40^\circ \text{ to } +105^\circ \text{C}$	SO-8	98 Units / Rail
	MC33202DR2		SO-8	2500 Units / Tape & Reel
	MC33202DMR2		Micro-8	4000 Units / Tape & Reel
	MC33202P		Plastic DIP	50 Units / Rail
	MC33202VD	$T_A = -55^\circ \text{ to } 125^\circ \text{C}$	SO-8	98 Units / Rail
	MC33202VDR2		SO-8	2500 Units / Tape & Reel
	MC33202VP		Plastic DIP	50 Units / Rail
Quad	MC33204D	$T_A = -40^\circ \text{ to } +105^\circ \text{C}$	SO-14	55 Units / Rail
	MC33204DR2		SO-14	2500 Units / Tape & Reel
	MC33204DTB		TSSOP-14	96 Units / Rail
	MC33204DTBR2		TSSOP-14	2500 Units / Tape & Reel
	MC33204P	$T_A = -55^\circ \text{ to } 125^\circ \text{C}$	Plastic DIP	25 Units / Rail
	MC33204VD		SO-14	55 Units / Rail
	MC33204VDR2		SO-14	2500 Units / Tape & Reel
	MC33204VP		Plastic DIP	25 Units / Rail

MARKING DIAGRAMS

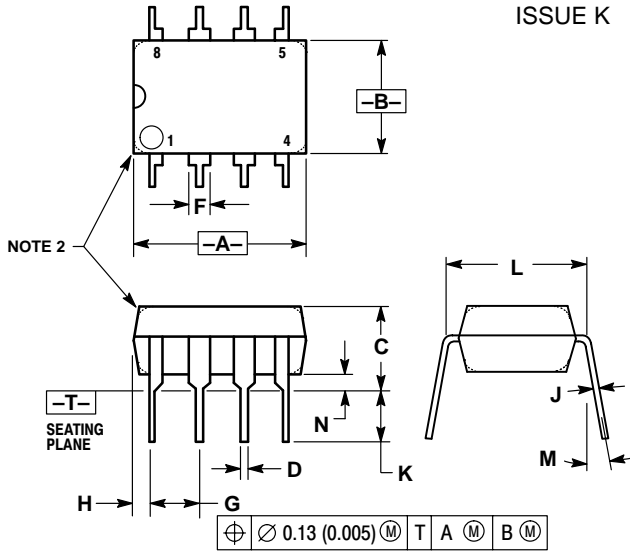


x = 1 or 2
 A = Assembly Location
 WL, L = Wafer Lot
 YY, Y = Year
 WW, W = Work Week

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PACKAGE DIMENSIONS

PDIP-8
P, VP SUFFIX
CASE 626-05
ISSUE K

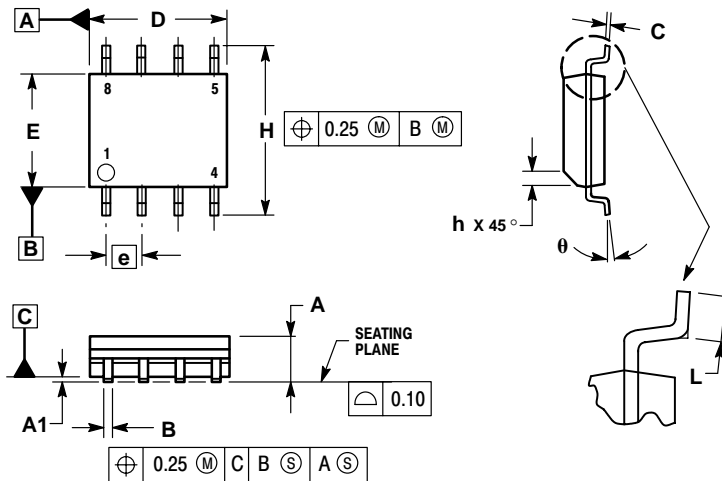


NOTES:

1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
B	6.10	6.60	0.240	0.260
C	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	---	10°	---	10°
N	0.76	1.01	0.030	0.040

SO-8
D, VD SUFFIX
CASE 751-06
ISSUE T



NOTES:

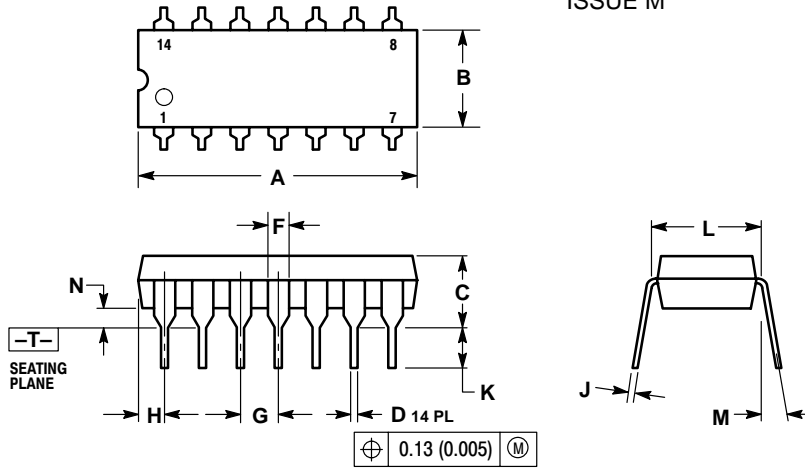
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS ARE IN MILLIMETER.
3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	1.35	1.75
A1	0.10	0.25
B	0.35	0.49
C	0.19	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.25
θ	0°	7°

MC33201, MC33202, MC33204

PACKAGE DIMENSIONS

PDIP-14
P, VP SUFFIX
 CASE 646-06
 ISSUE M

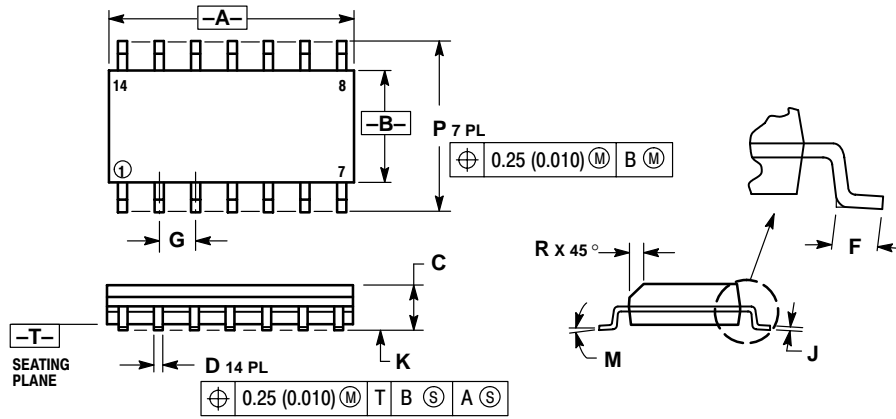


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.715	0.770	18.16	18.80
B	0.240	0.260	6.10	6.60
C	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
H	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
M	---	10°	---	10°
N	0.015	0.039	0.38	1.01

SO-14
D, VD SUFFIX
 CASE 751A-03
 ISSUE F



NOTES:

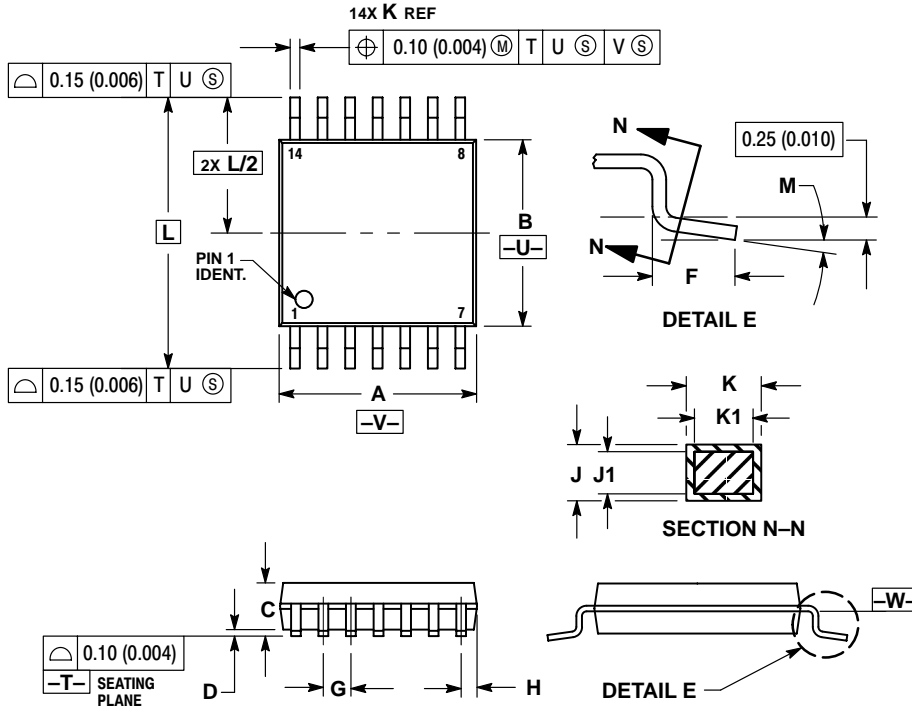
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

MC33201, MC33202, MC33204

PACKAGE DIMENSIONS

TSSOP-14
DTB SUFFIX
CASE 948G-01
ISSUE O



NOTES:

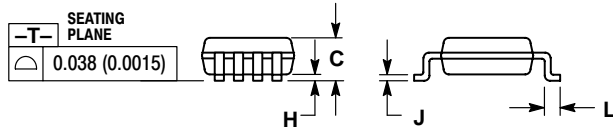
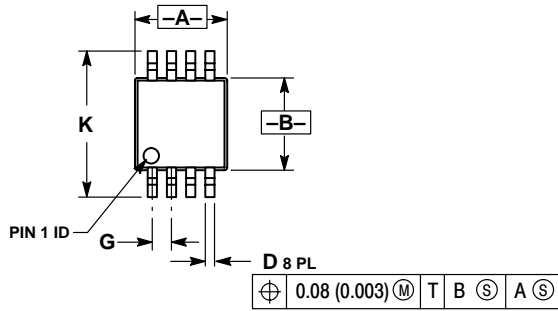
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

MC33201, MC33202, MC33204

PACKAGE DIMENSIONS

Micro-8
DM SUFFIX
CASE 846A-02
ISSUE E



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	---	1.10	---	0.043
D	0.25	0.40	0.010	0.016
G	0.65 BSC		0.026 BSC	
H	0.05	0.15	0.002	0.006
J	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

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